UNR32A3

Silicon NPN epitaxial planar type

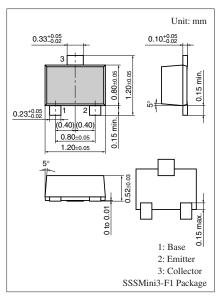
For digital circuits

Features

- Suitable for high-density mounting and downsizing of the equipment
- Contribute to low power consumption

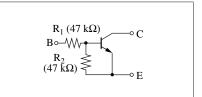
Absolute maximum matings $T_a = 25$ C			
Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	50	V
Collector-emitter voltage (Base open)	V _{CEO}	50	V
Collector current	I _C	80	mA
Total power dissipation	P _T	100	mW
Junction temperature	Tj	125	°C
Storage temperature	T _{stg}	-55 to +125	°C

Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol: FN

Internal Connection

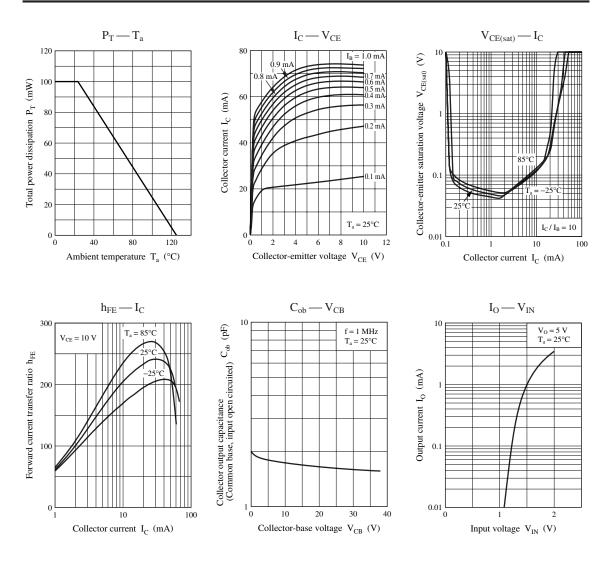


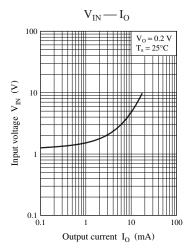
Parameter Symbol Conditions Min Max Unit Typ Collector-base voltage (Emitter open) $I_C = 10 \ \mu A, I_E = 0$ 50 V V_{CBO} VCEO $I_{C} = 2 \text{ mA}, I_{B} = 0$ 50 V Collector-emitter voltage (Base open) Collector-base cutoff current (Emitter open) $V_{CB} = 50 \text{ V}, I_E = 0$ I_{CBO} 0.1μΑ $V_{CE} = 50 \text{ V}, I_B = 0$ Collector-emitter cutoff current (Base open) 0.5 μΑ I_{CEO} $V_{EB} = 6 V, I_C = 0$ Emitter-base cutoff current (Collector open) 0.1 I_{EBO} mA Forward current transfer ratio h_{FE} $V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$ 80 ____ $I_{C} = 10 \text{ mA}, I_{B} = 0.3 \text{ mA}$ 0.25 v Collector-emitter saturation voltage V_{CE(sat)} $V_{CC} = 5 V, V_B = 0.5 V, R_L = 1 k\Omega$ Output voltage high-level VOH 4.9 v Output voltage low-level VOL $V_{CC} = 5 V, V_B = 3.5 V, R_L = 1 k\Omega$ 0.2 V Input resistance R_1 -30% 47 +30%kΩ Resistance ratio R_1 / R_2 0.8 1.01.2 Transition frequency $V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$ 150 MHz \mathbf{f}_{T}

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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